

Micropower, Over-The-Top SOT-23, Rail-to-Rail Input and Output Op Amp

FEATURES

- Operates with Inputs Above V⁺
- Rail-to-Rail Input and Output
- Micropower: 55µA Supply Current Max
- Small SOT-23 Package
- Low Input Offset Voltage: 800µV Max
- Single Supply Input Range: 0V to 18V
- High Output Current: 18mA Min
- Specified on 3V, 5V and ±5V Supplies
- Output Shutdown on 6-Lead Version
- Reverse Battery Protection to 18V
- High Voltage Gain: 1500V/mV
- Gain Bandwidth Product: 200kHz
- Slew Rate: 0.07V/us
- Operating Temperature Range: -40°C to 85°C

APPLICATIONS

- Portable Instrumentation
- Battery- or Solar-Powered Systems
- Sensor Conditioning
- Supply Current Sensing
- Battery Monitoring
- MUX Amplifiers
- 4mA to 20mA Transmitters

DESCRIPTION

The LT®1782 is a 200kHz op amp available in the small SOT-23 package that operates on all single and split supplies with a total voltage of 2.5V to 18V. The amplifier draws less than $55\mu A$ of quiescent current and has reverse battery protection, drawing negligible current for reverse supply voltages up to 18V.

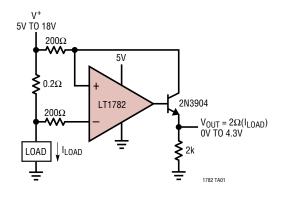
The input range of the LT1782 includes ground, and a unique feature of this device is its Over-The-Top[™] operation capability with either or both of its inputs above the positive rail. The inputs handle 18V both differential and common mode, independent of supply voltage. The input stage incorporates phase reversal protection to prevent false outputs from occurring even when the inputs are 9V below the negative supply.

The LT1782 can drive loads up to 18mA and still maintain rail-to-rail capability. A shutdown feature on the 6-lead version can disable the part, making the output high impedance and reducing quiescent current to $5\mu A$. The LT1782 op amp is available in the 5- and 6-lead SOT-23 packages. For applications requiring higher speed, refer to the LT1783.

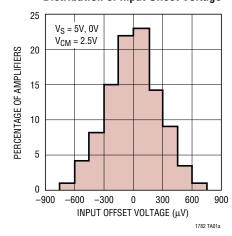
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TYPICAL APPLICATION

Positive Supply Rail Current Sense



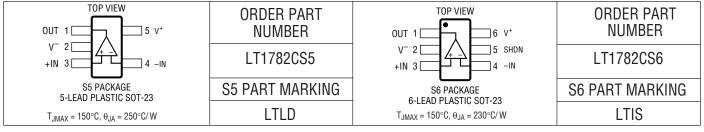
Distribution of Input Offset Voltage



ABSOLUTE MAXIMUM RATINGS (Note 1)

Total Supply Voltage (V+ to V ⁻)	18V
Input Differential Voltage	18V
Input Pin Voltage to V ⁻ +24V/-	-10V
Shutdown Pin Voltage Above V ⁻	18V
Shutdown Pin Current ±10	0mA
Output Short-Circuit Duration (Note 2) Indef	inite

PACKAGE/ORDER INFORMATION



Consult factory for Industrial and Military grade parts.

ELECTRICAL CHARACTERISTICS

The \bullet denotes specifications which apply over the specified temperature range, otherwise specifications are $T_A = 25^{\circ}C$. $V_S = 3V$, OV; $V_S = 5V$, OV, $V_{CM} = V_{OUT} = half supply, for the 6-lead part <math>V_{PIN5} = OV$, pulse power tested unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{OS}	Input Offset Voltage	$T_A = 25^{\circ}C$ $0^{\circ}C \le T_A \le 70^{\circ}C$	•		400	800 950	μV μV
	Input Offset Voltage Drift (Note 7)	$0^{\circ}C \leq T_A \leq 70^{\circ}C$	•		2	5	μV/°C
I _{OS}	Input Offset Current	V _{CM} = 18V (Note 3)	•		0.7	2	nA μA
I _B	Input Bias Current	V _{CM} = 18V (Note 3) SHDN or V _S = 0V, V _{CM} = 0V to 18V	•		8 6 0.1	15 12	nA μA nA
	Input Bias Current Drift	$0^{\circ}\text{C} \le \text{T}_{\text{A}} \le 70^{\circ}\text{C}$	•		0.01		nA/°C
	Input Noise Voltage	0.1Hz to 10Hz			1		μV _{P-P}
e _n	Input Noise Voltage Density	f = 1kHz			50		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz			0.05		pA/√Hz
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = 0V to (V _{CC} – 1V) Common Mode, V _{CM} = 0V to 18V		3.4 1.5	6.5 5 3		MΩ GΩ MΩ
C _{IN}	Input Capacitance				5		pF
	Input Voltage Range		•	0		18	V
CMRR	Common Mode Rejection Ratio (Note 3)	$V_{CM} = 0V \text{ to } V_{CC} - 1V$ $V_{CM} = 0V \text{ to } 18V \text{ (Note 6)}$	•	90 68	100 80		dB dB
PSRR	Power Supply Rejection Ratio	$V_S = 3V \text{ to } 12.5V, V_{CM} = V_0 = 1V$	•	90	100		dB
A _{VOL}	Large-Signal Voltage Gain	$V_S = 3V$, $V_0 = 500$ mV to 2.5V, $R_L = 10$ k $V_S = 3V$, 0° C $\leq T_A \leq 70^{\circ}$ C	•	200 133	1500		V/mV V/mV
		$V_S = 5V$, $V_0 = 500$ mV to 4.5V, $R_L = 10$ k $V_S = 5V$, 0° C $\leq T_A \leq 70^{\circ}$ C	•	400 250	1500		V/mV V/mV



ELECTRICAL CHARACTERISTICS

The ullet denotes specifications which apply over the specified temperature range, otherwise specifications are $T_A = 25^{\circ}C$. $V_S = 3V$, 0V; $V_S = 5V$, 0V, $V_{CM} = V_{OUT} = half$ supply, for the 6-lead part $V_{PIN5} = 0V$, pulse power tested unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
V _{OL}	Output Voltage Swing LOW	No Load I _{SINK} = 5mA V _S = 5V, I _{SINK} = 10mA	•		3 200 400	8 500 800	mV mV mV
V _{OH}	Output Voltage Swing HIGH	$V_S = 3V$, No Load $V_S = 3V$, $I_{SOURCE} = 5mA$	•	2.91 2.6	2.94 2.8		V
		V _S = 5V, No Load V _S = 5V, I _{SOURCE} = 10mA	•	4.91 4.5	4.94 4.74		V V
I _{SC}	Short-Circuit Current (Note 2)	$V_S = 3V$, Short to GND $V_S = 3V$, Short to V_{CC}		5 15	10 30		mA mA
		$V_S = 5V$, Short to GND $V_S = 5V$, Short to V_{CC}		15 20	30 40		mA mA
	Minimum Supply Voltage		•		2.5	2.7	V
	Reverse Supply Voltage	$I_S = -100 \mu A$	•	18			V
Is	Supply Current (Note 4)		•		40	55 60	μΑ μΑ
	Supply Current, SHDN	V _{PIN5} = 2V, No Load (Note 8)	•		5	15	μА
I _{SHDN}	Shutdown Pin Current	V _{PIN5} = 0.3V, No load (Note 8) V _{PIN5} = 2V, No Load (Note 8) V _{PIN5} = 5V, No Load (Note 8)	•		0.5 2 5	8	nA μA μA
	Shutdown Output Leakage Current	V _{PIN5} = 2V, No Load (Note 8)	•		0.05	1	μA
	Maximum Shutdown Pin Current	V _{PIN5} = 18V, No Load (Note 8)	•		10	30	μА
V_L	Shutdown Pin Input Low Voltage	(Note 8)	•			0.3	V
V _H	Shutdown Pin Input High Voltage	(Note 8)	•	2			V
t _{ON}	Turn-On Time	V _{PIN5} = 5V to 0V, R _L = 10k (Note 8)			100		μS
t _{OFF}	Turn-Off Time	V _{PIN5} = 0V to 5V, R _L = 10k (Note 8)			6		μS
GBW	Gain Bandwidth Product (Note 3)	$ f = 5kHz $ $0^{\circ}C \le T_{A} \le 70^{\circ}C $	•	110 100	200		kHz kHz
SR	Slew Rate (Note 5)	$A_V = -1, R_L = \infty$ $0^{\circ}C \le T_A \le 70^{\circ}C$	•	0.035 0.031	0.07		V/µs V/µs
t _S	Settling Time	$V_S = 5V$, $\Delta V_{OUT} = 2V$ to 0.1%, $A_V = -1$			45		μS
THD	Distortion	$V_S = 3V$, $V_0 = 2V_{P-P}$, $A_V = 1$, $R_L = 10k$, $f = 1kHz$			0.003		%
FPBW	Full-Power Bandwidth (Note 9)	$V_{OUT} = 2V_{P-P}$			11		kHz

$V_S=\pm 5 V,~V_{CM}=0 V, V_{OUT}=0 V,~for~the~6-lead~part~V_{SHDN}=V^-$

V _{OS}	Input Offset Voltage	$T_A = 25^{\circ}C$ $0^{\circ}C \le T_A \le 70^{\circ}C$	•	500	900 1050	μV μV
	Input Offset Voltage Drift (Note 7)	$0^{\circ}C \leq T_A \leq 70^{\circ}C$	•	2	5	μV/°C
I _{OS}	Input Offset Current		•	0.7	2	nA
I _B	Input Bias Current		•	8	15	nA
	Input Bias Current Drift	$0^{\circ}C \leq T_A \leq 70^{\circ}C$	•	0.01		nA/°C
	Input Noise Voltage	0.1Hz to 10Hz		1		μV _{P-P}
en	Input Noise Voltage Density	f = 1kHz		50		nV/√Hz
i _n	Input Noise Current Density	f = 1kHz		0.05		pA/√Hz



ELECTRICAL CHARACTERISTICS

The ullet denotes specifications which apply over the specified temperature range, otherwise specifications are $T_A = 25^{\circ}C$. $V_S = \pm 5V$, $V_{CM} = 0V$, $V_{OUT} = 0V$, for the 6-lead part $V_{SHDN} = V^-$, unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS		MIN	TYP	MAX	UNITS
R _{IN}	Input Resistance	Differential Common Mode, V _{CM} = -5V to 13V	•	3.4 1.5	6.5 3		MΩ MΩ
C _{IN}	Input Capacitance				5		pF
	Input Voltage Range		•	-5		13	V
CMRR	Common Mode Rejection Ratio	$V_{CM} = -5V$ to 13V	•	68	80		dB
A _{VOL}	Large-Signal Voltage Gain	$V_0 = \pm 4V, R_L = 10k$ $0^{\circ}C \le T_A \le 70^{\circ}C$	•	55 40	150		V/mV V/mV
V _{OL}	Output Voltage Swing LOW	No Load I _{SINK} = 5mA I _{SINK} = 10mA	•		-4.997 -4.8 -4.6	-4.992 -4.5 -4.2	V V
V _{OH}	Output Voltage Swing HIGH	No Load I _{SOURCE} = 5mA I _{SOURCE} = 10mA	•	4.91 4.6 4.5	4.94 4.8 4.74		V V V
I _{SC}	Short-Circuit Current (Note 2)	Short to GND $0^{\circ}\text{C} \leq \text{T}_{\text{A}} \leq 70^{\circ}\text{C}$	•	18 15	30		mA mA
PSRR	Power Supply Rejection Ratio	$V_S = \pm 1.5 V \text{ to } \pm 9 V$	•	90	100		dB
Is	Supply Current		•		45	60 65	μA μA
	Supply Current, SHDN	$V_{PIN5} = -3V$, $V_S = \pm 5V$, No Load (Note 8)	•		6	20	μА
I _{SHDN}	Shutdown Pin Current	$V_{PIN5} = -4.7V$, $V_{S} = \pm 5V$, No load (Note 8) $V_{PIN5} = -3V$, $V_{S} = \pm 5V$, No Load (Note 8)	•		0.5 2	8	nA μA
	Maximum Shutdown Pin Current	$V_{PIN5} = 9V, V_{S} = \pm 9V \text{ (Note 8)}$	•		10	30	μА
	Shutdown Output Leakage Current	$V_{PIN5} = -7V$, $V_S = \pm 9V$, No Load (Note 8)	•		0.05	1	μА
V_L	Shutdown Pin Input Low Voltage	$V_S = \pm 5V$ (Note 8)	•			-4.7	V
V_{H}	Shutdown Pin Input High Voltage	$V_S = \pm 5V$ (Note 8)	•	-3			V
t _{ON}	Turn-On Time	$V_{PIN5} = 0V \text{ to } -5V, R_L = 10k \text{ (Note 8)}$	•		100		μs
t _{OFF}	Turn-Off Time	$V_{PIN5} = -5V \text{ to } 0V, R_L = 10k \text{ (Note 8)}$	•		6		μs
GBW	Gain Bandwidth Product	$ f = 5kHz 0°C \le T_A \le 70°C $	•	120 110	225		kHz kHz
SR	Slew Rate	$A_V=-1,~R_L=\infty,~V_0=\pm 4V,~Measured~at~V_0=\pm 2V$ $0^{\circ}C\leq T_A\leq 70^{\circ}C$	•	0.0375 0.033	0.075		V/µs V/µs
t _S	Settling Time	$\Delta V_{OUT} = 4V \text{ to } 0.1\%, A_V = 1$			50		μs
FPBW	Full-Power Bandwidth (Note 9)	$V_{OUT} = 8V_{P-P}$			3		kHz

Note 1: Absolute Maximum Ratings are those values beyond which the life of a device may be impaired.

Note 2: A heat sink may be required to keep the junction temperature below absolute maximum.

Note 3: $V_S = 5V$ limits are guaranteed by correlation to $V_S = 3V$ and $V_S = \pm 5V$ or $V_S = \pm 9V$ tests.

Note 4: $V_S=3V$ limits are guaranteed by correlation to $V_S=5V$ and $V_S=\pm5V$ or $V_S=\pm9V$ tests.

Note 5: Guaranteed by correlation to slew rate at $V_S = \pm 5V$, and GBW at $V_S = 3V$ and $V_S = \pm 5V$ tests.

Note 6: This specification implies a typical input offset voltage of 1.8mV at $V_{CM}=18V$ and a maximum input offset voltage of 7.2mV at $V_{CM}=18V$.

Note 7: This parameter is not 100% tested.

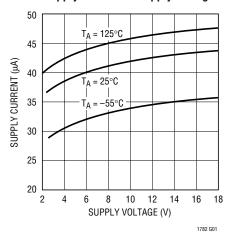
Note 8: Specifications apply to 6-lead SOT-23 with shutdown.

Note 9: Full-power bandwidth is calculated for the slew rate. FPBW = $SR/2\pi V_P$.

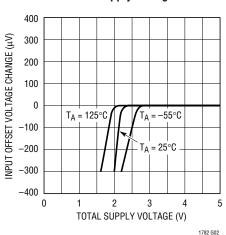
Note 10: The LT1782 is guaranteed functional over the operating temperature range -40° C to 85° C.



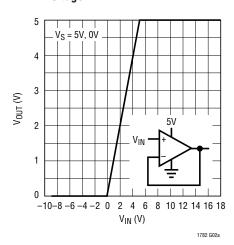
Supply Current vs Supply Voltage



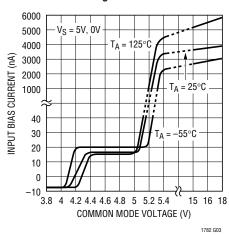
Minimum Supply Voltage



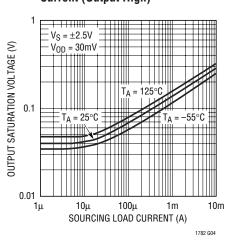
Output Voltage vs Large Input Voltage



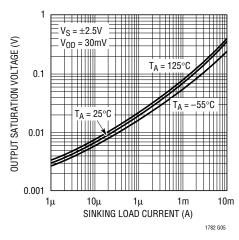
Input Bias Current vs Common Mode Voltage



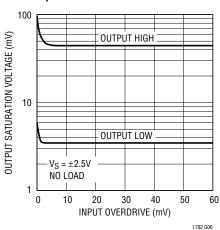
Output Saturation Voltage vs Load Current (Output High)



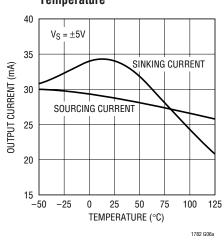
Output Saturation Voltage vs Load Current (Output Low)



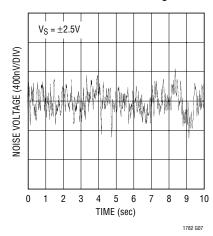
Output Saturation Voltage vs Input Overdrive

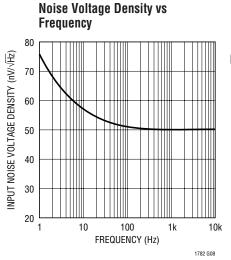


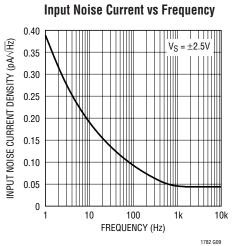
Output Short-Circuit Current vs Temperature

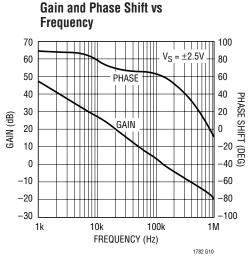


0.1Hz to 10Hz Noise Voltage

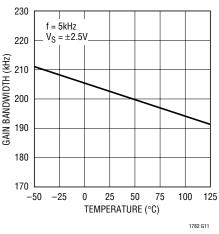


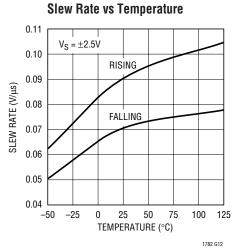


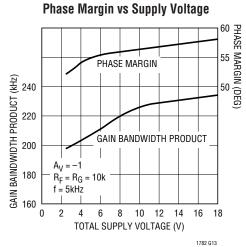




Gain Bandwidth Product vs Temperature

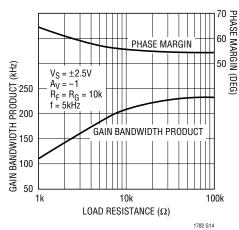


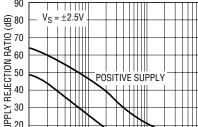


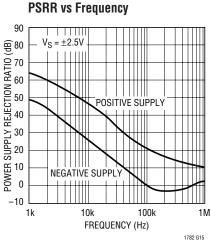


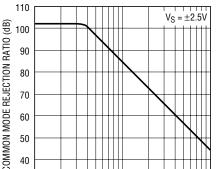
Gain Bandwidth Product and

Gain Bandwidth Product and Phase Margin vs Load Resistance

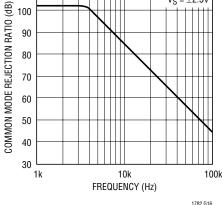








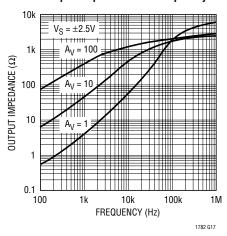
CMRR vs Frequency



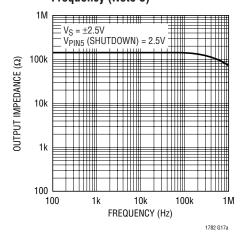




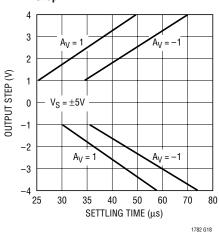
Output Impedance vs Frequency



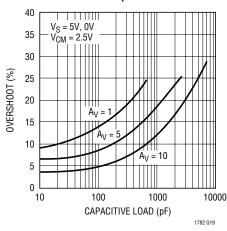
Disabled Output Impedance vs Frequency (Note 8)



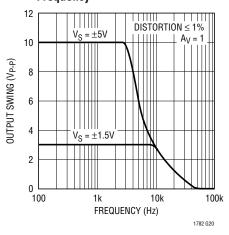
Settling Time to 0.1% vs Output Step



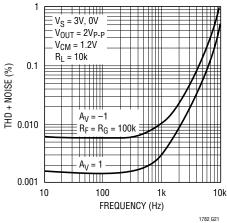
Capacitive Load Handling Overshoot vs Capacitive Load



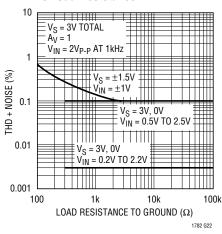
Undistorted Output Swing vs Frequency



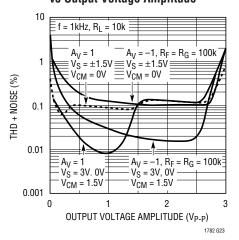
Total Harmonic Distortion + Noise vs Frequency



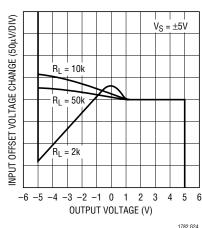
Total Harmonic Distortion + Noise vs Load Resistance

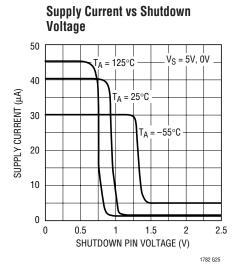


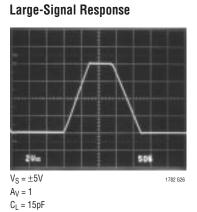
Total Harmonic Distortion + Noise vs Output Voltage Amplitude

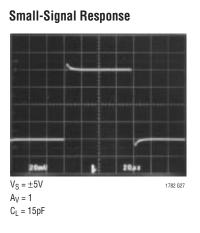


Open-Loop Gain









APPLICATIONS INFORMATION

Supply Voltage

The positive supply pin of the LT1782 should be bypassed with a small capacitor (typically $0.1\mu F$) within an inch of the pin. When driving heavy loads, an additional $4.7\mu F$ electrolytic capacitor should be used. When using split supplies, the same is true for the negative supply pin.

The LT1782 is protected against reverse battery voltages up to 18V. In the event a reverse battery condition occurs, the supply current is typically less than 1nA.

Inputs

The LT1782 has two input stages, NPN and PNP (see the Simplified Schematic), resulting in three distinct operating regions as shown in the Input Bias Current vs Common Mode typical performance curve.

For input voltages about 0.8V or more below V⁺, the PNP input stage is active and the input bias current is typically –8nA. When the input common mode voltage is within 0.5V of the positive rail, the NPN stage is operating and the input bias current is typically 15nA. Increases in temperature will cause the voltage at which operation switches from the PNP input stage to the NPN input stage to move towards V⁺. The input offset voltage of the NPN stage is untrimmed and is typically 1.8mV.

A Schottky diode in the collector of the input NPN transistors, along with special geometries for these NPN transistors, allows the LT1782 to operate with either or both of its inputs above V⁺. At about 0.3V above V⁺, the NPN input transistor is fully saturated and the input bias current is typically $4\mu A$ at room temperature. The input offset voltage is typically 1.8mV when operating above V⁺. The LT1782 will operate with its inputs 18V above V⁻ regardless of V⁺.

The inputs are protected against excursions as much as 10V below V^- by an internal 6k resistor in series with each input and a diode from the input to the negative supply. The input stage of the LT1782 incorporates phase reversal protection to prevent the output from phase reversing for inputs up to 9V below V^- . There are no clamping diodes between the inputs and the maximum differential input voltage is 18V.

Output

The output of the LT1782 can swing to within 60mV of the positive rail with no load and within 3mV of the negative rail with no load. When monitoring voltages within 60mV of the positive rail or within 3mV of the negative rail, gain should be taken to keep the output from clipping. The LT1782 can sink and source over 30mA at ±5V supplies,



APPLICATIONS INFORMATION

sourcing current is reduced to 10mA at 3V total supplies as noted in the Electrical Characteristics.

The LT1782 is internally compensated to drive at least 600pF of capacitance under any output loading conditions. A $0.22\mu F$ capacitor in series with a 150Ω resistor between the output and ground will compensate these amplifiers for larger capacitive loads, up to 10,000pF, at all output currents.

Distortion

There are two main contributors to distortion in op amps: output crossover distortion as the output transitions from sourcing to sinking current, and distortion caused by nonlinear common mode rejection. If the op amp is operating inverting, there is no common mode induced distortion. If the op amp is operating in the PNP input stage (input is not within 0.8V of V+), the CMRR is very good, typically 100dB. When the LT1782 switches between input stages, there is significant nonlinearity in the CMRR. Lower load resistance increases the output crossover distortion but has no effect on the input stage transition distortion. For lowest distortion, the LT1782 should be

operated single supply, with the output always sourcing current and with the input voltage swing between ground and ($V^+ - 0.8V$). See the Typical Performance Characteristics curves, "Total Harmonic Distortion + Noise vs Ouput Voltage Amplitude."

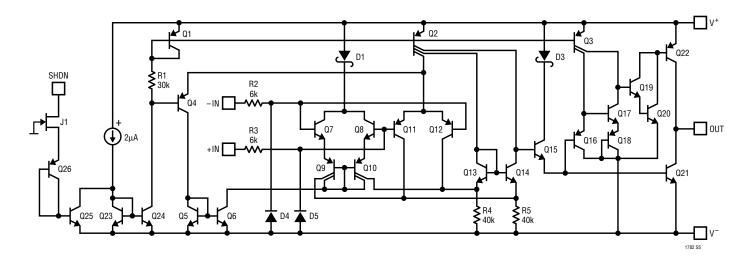
Gain

The open-loop gain is almost independent of load when the output is sourcing current. This optimizes performance in single supply applications where the load is returned to ground. The typical performance curve of open-loop gain for various loads shows the details.

Shutdown

The 6-lead part includes a shutdown feature that disables the part, reducing quiescent current and making the output high impedance. The part can be shut down by bringing the SHDN pin 1.2V or more above V^- . When shut down, the supply current is about $5\mu A$ and the output leakage current is less than $1\mu A$ ($V^- \leq V_{OUT} \leq V^+$). In normal operation, the SHDN pin can be tied to V^- or left floating. See the Typical Performance Characteristics curves, "Supply Current vs Shutdown Pin Voltage."

SIMPLIFIED SCHEMATIC



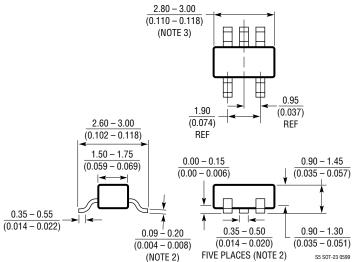


PACKAGE DESCRIPTION

 $\label{lem:decomposition} \textbf{Dimensions in inches (millimeters) unless otherwise noted.}$

S5 Package 5-Lead Plastic SOT-23

(LTC DWG # 05-08-1633)



NOTE:

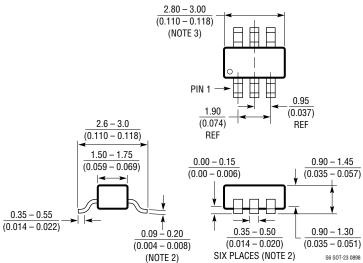
- DIMENSIONS ARE IN MILLIMETERS
- 2. DIMENSIONS ARE INCLUSIVE OF PLATING
- 3. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
- 4. MOLD FLASH SHALL NOT EXCEED 0.254mm
- 5. PACKAGE EIAJ REFERENCE IS SC-74A (EIAJ)

PACKAGE DESCRIPTION

Dimensions in inches (millimeters) unless otherwise noted.

S6 Package 6-Lead Plastic SOT-23

(LTC DWG # 05-08-1634)

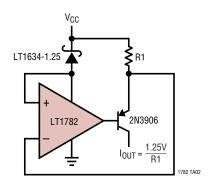


NOTE:

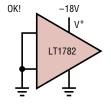
- 1. DIMENSIONS ARE IN MILLIMETERS
- 2. DIMENSIONS ARE INCLUSIVE OF PLATING
- 3. DIMENSIONS ARE EXCLUSIVE OF MOLD FLASH AND METAL BURR
- 4. MOLD FLASH SHALL NOT EXCEED 0.254mm
- 5. PACKAGE EIAJ REFERENCE IS SC-74A (EIAJ)

TYPICAL APPLICATIONS

Current Source

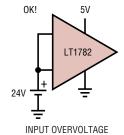


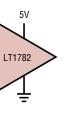
Protected Fault Conditions



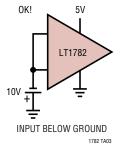
REVERSE BATTERY

OK!





INPUT DIFFERENTIAL VOLTAGE



RELATED PARTS

PART NUMBER	DESCRIPTION	COMMENTS
LT1783	Micropower Over-The-Top SOT-23 Rail-to-Rail Input and Output Op Amp	SOT-23 Package, Micropower 210μA per Amplifier, Rail-to-Rail Input and Output , 1.25MHz GBW
LT1490/LT1491	Dual/Quad Over-The-Top Micropower Rail-to-Rail Input and Output Op Amps	Single Supply Input Range: -0.4V to 44V, Micropower 50µA per Amplifier, Rail-to-Rail Input and Output , 200kHz GBW
LT1636	Single Over-The-Top Micropower Rail-to-Rail Input and Output Op Amp	$55\mu A$ Supply Current, V_{CM} Extends 44V Above $V_{EE},$ Independent of $V_{CC},$ MSOP Package, Shutdown Function
LT1638/LT1639	Dual/Quad, 1.2MHz, 0.4V/µs, Over-The-Top Micropower Rail-to-Rail Input and Output Op Amps	170µA Supply Current, Single Supply Input Range: -0.4V to 44V, Rail-to-Rail Input and Output